



Standard Recovery Diodes (Hockey PUK Version), 3000 A



DO-200AC (K-PUK)

FEATURES

- Wide current range
- High voltage ratings up to 2500 V
- High surge current capabilities
- Diffused junction
- Hockey PUK version
- Case style DO-200AC (K-PUK)
- Material categorization: For definitions of compliance please see www.vishay.com/doc?99912



RoHS
COMPLIANT

TYPICAL APPLICATIONS

- Converters
- Power supplies
- Machine tool controls
- High power drives
- Medium traction applications

PRODUCT SUMMARY	
$I_{F(AV)}$	3000 A
Package	DO-200AC (K-PUK)
Circuit configuration	Single diode

MAJOR RATINGS AND CHARACTERISTICS			
PARAMETER	TEST CONDITIONS	VALUES	UNITS
$I_{F(AV)}$		3000	A
	T_{hs}	55	°C
$I_{F(RMS)}$		5000	A
	T_{hs}	25	°C
I_{FSM}	50 Hz	31 000	A
	60 Hz	32 460	
I^2t	50 Hz	4810	kA ² s
	60 Hz	4390	
V_{RRM}	Range	1200 to 2500	V
T_J		-40 to 180	°C

ELECTRICAL SPECIFICATIONS

VOLTAGE RATINGS				
TYPE NUMBER	VOLTAGE CODE	V_{RRM} , MAXIMUM REPETITIVE PEAK REVERSE VOLTAGE V	V_{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I_{RRM} MAXIMUM AT $T_J = 180$ °C mA
VS-SD2500C..K	12	1200	1300	75
	16	1600	1700	
	20	2000	2100	
	25	2500	2600	



FORWARD CONDUCTION					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum average forward current at heatsink temperature	$I_{F(AV)}$	180° conduction, half sine wave Double side (single side) cooled		3000 (1550)	A
				55 (85)	°C
Maximum RMS forward current	$I_{F(RMS)}$	25 °C heatsink temperature double side cooled		5000	
Maximum peak, one-cycle forward, non-repetitive surge current	I_{FSM}	t = 10 ms	No voltage reappplied	Sinusoidal half wave, initial $T_J = T_J$ maximum	A
		t = 8.3 ms			
		t = 10 ms	100 % V_{RRM} reappplied		
		t = 8.3 ms			
Maximum I^2t for fusing	I^2t	t = 10 ms	No voltage reappplied		kA ² s
		t = 8.3 ms			
		t = 10 ms	100 % V_{RRM} reappplied		
		t = 8.3 ms			
Maximum $I^2\sqrt{t}$ for fusing	$I^2\sqrt{t}$	t = 0.1 to 10 ms, no voltage reappplied		48 100	kA ² √s
Low level value of threshold voltage	$V_{F(TO)1}$	$(16.7 \% \times \pi \times I_{F(AV)} < I < \pi \times I_{F(AV)})$, $T_J = T_J$ maximum		0.76	V
High level value of threshold voltage	$V_{F(TO)2}$	$(I > \pi \times I_{F(AV)})$, $T_J = T_J$ maximum		0.97	
Low level value of forward slope resistance	r_{f1}	$(16.7 \% \times \pi \times I_{F(AV)} < I < \pi \times I_{F(AV)})$, $T_J = T_J$ maximum		0.16	mW
High level value of forward slope resistance	r_{f2}	$(I > \pi \times I_{F(AV)})$, $T_J = T_J$ maximum		0.13	
Maximum forward voltage drop	V_{FM}	$I_{pk} = 4000$ A, $T_J = T_J$ maximum $t_p = 10$ ms sinusoidal wave		1.41	V

THERMAL AND MECHANICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum junction operating temperature range	T_J			-40 to 180	°C
Maximum storage temperature range	T_{Stg}			-55 to 200	
Maximum thermal resistance, junction to heatsink	R_{thJ-hs}	DC operation single side cooled		0.042	K/W
		DC operation double side cooled		0.020	
Mounting force, ± 10 %				22 250 (2250)	N (kg)
Approximate weight				425	g
Case style		See dimensions - link at the end of datasheet		DO-200AC (K-PUK)	

ΔR_{thJ-hs} CONDUCTION						
CONDUCTION ANGLE	SINUSOIDAL CONDUCTION		RECTANGULAR CONDUCTION		TEST CONDITIONS	UNITS
	SINGLE SIDE	DOUBLE SIDE	SINGLE SIDE	DOUBLE SIDE		
180°	0.002	0.002	0.001	0.001	$T_J = T_J$ maximum	K/W
120°	0.002	0.002	0.002	0.002		
90°	0.003	0.003	0.003	0.003		
60°	0.004	0.004	0.004	0.004		
30°	0.007	0.007	0.007	0.007		

Note

- The table above shows the increment of thermal resistance R_{thJ-hs} when devices operate at different conduction angles than DC

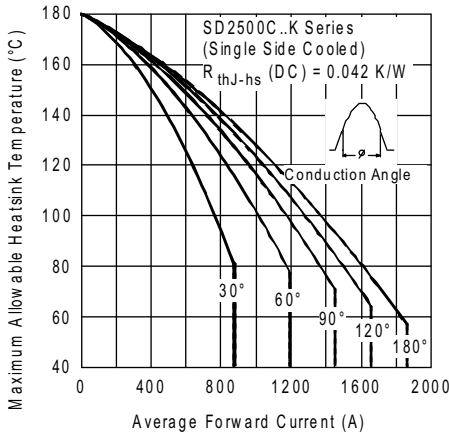


Fig. 1 - Current Ratings Characteristics

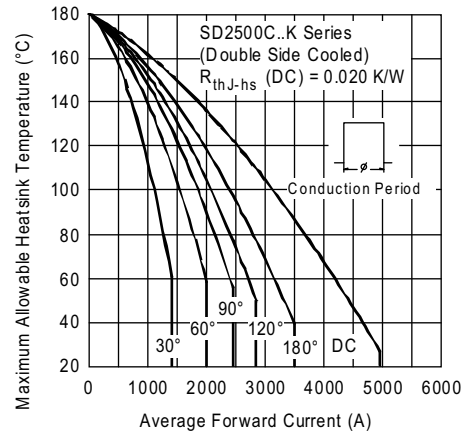


Fig. 4 - Current Ratings Characteristics

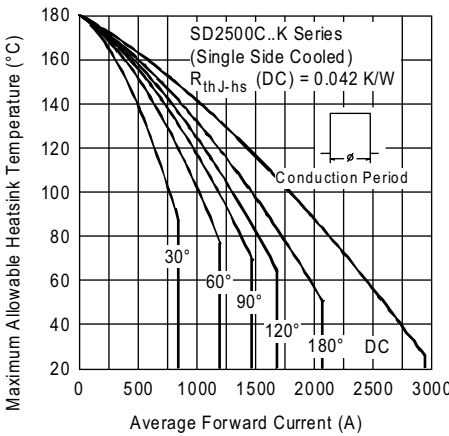


Fig. 2 - Current Ratings Characteristics

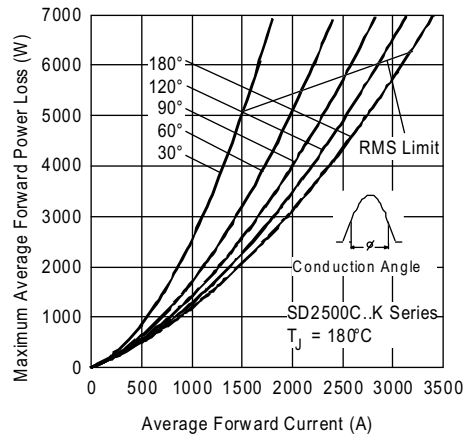


Fig. 5 - Forward Power Loss Characteristics

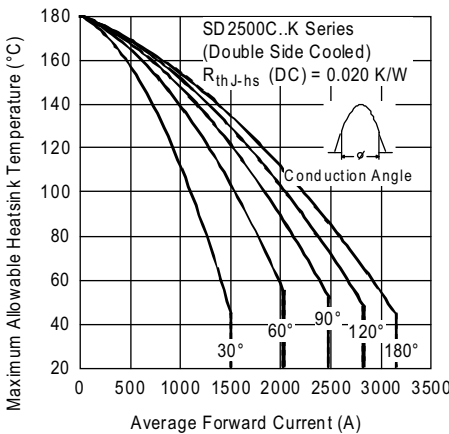


Fig. 3 - Current Ratings Characteristics

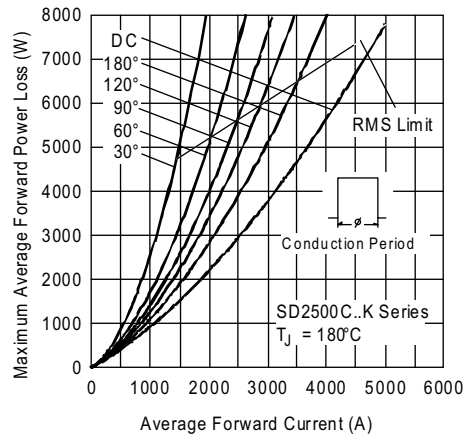


Fig. 6 - Forward Power Loss Characteristics

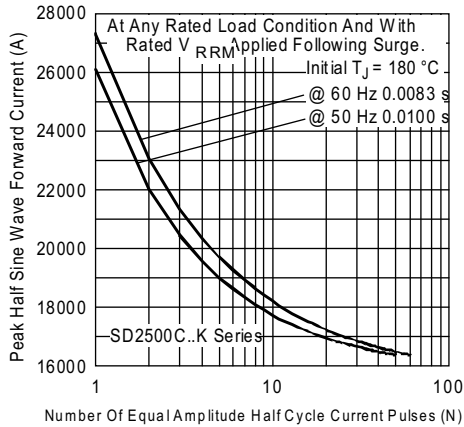


Fig. 7 - Maximum Non-Repetitive Surge Current Single and Double Side Cooled

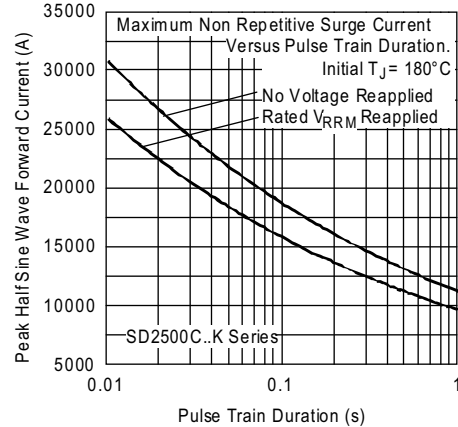


Fig. 8 - Maximum Non-Repetitive Surge Current Single and Double Side Cooled

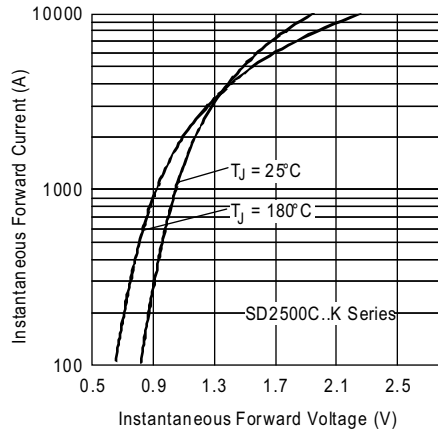


Fig. 9 - Forward Voltage Drop Characteristics

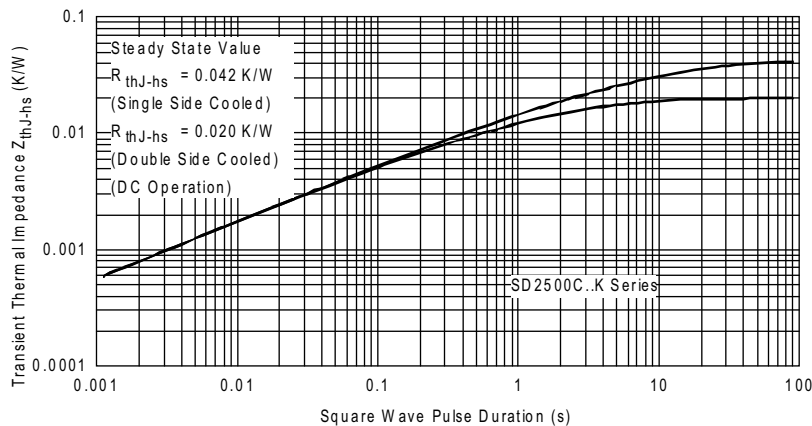
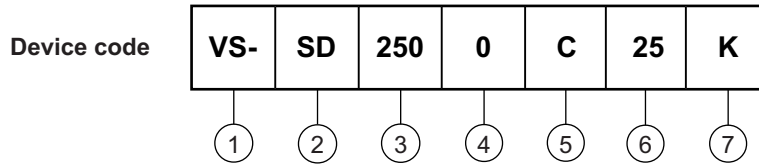


Fig. 10 - Thermal Impedance Z_{thJ-hs} Characteristics



ORDERING INFORMATION TABLE

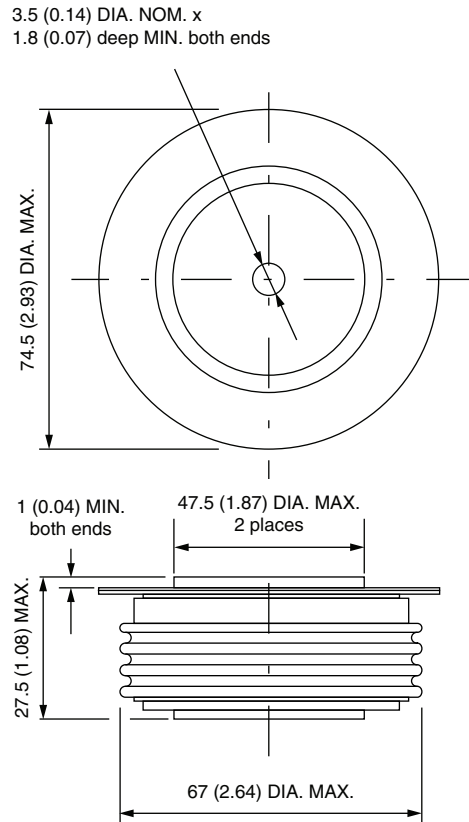


- 1** - Vishay Semiconductors product
- 2** - Diode
- 3** - Essential part number
- 4** - 0 = Standard recovery
- 5** - C = Ceramic PUK
- 6** - Voltage code x 100 = V_{RRM} (see Voltage Ratings table)
- 7** - K = PUK case DO-200AC (K-PUK)

LINKS TO RELATED DOCUMENTS	
Dimensions	www.vishay.com/doc?95247

DO-200AC (K-PUK)

DIMENSIONS in millimeters (inches)



Quote between upper and lower pole pieces has to be considered after application of mounting force (see Thermal and Mechanical Specifications)



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